

CY25AAJ-8F

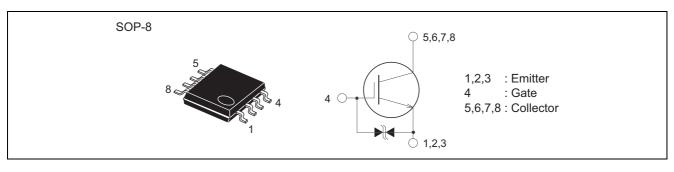
Nch IGBT for Strobe Flasher

REJ03G0283-0100 Rev.1.00 Aug.20.2004

Features

- V_{CES} : 400 V
- I_{CM} : 150 A
- Drive voltage :4 V

Outline



Applications

Strobe flasher for cameras

Maximum Ratings

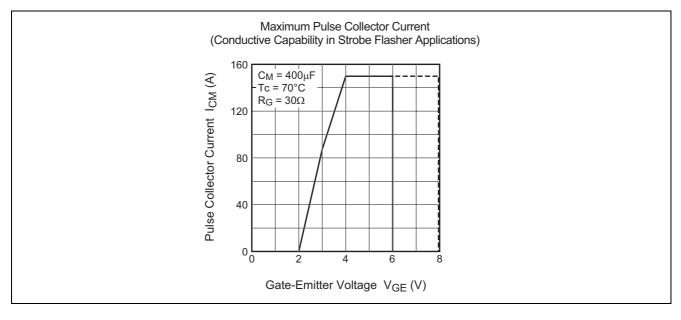
 $(Tc = 25^{\circ}C)$

Parameter	Symbol	Ratings	Unit	Conditions
Collector-emitter voltage	V _{CES}	400	V	$V_{GE} = 0 V$
Gate-emitter voltage	V _{GES}	±6	V	$V_{CE} = 0 V$
Peak gate-emitter voltage	V _{GEM}	±8	V	$V_{CE} = 0 V$, tw = 10 s
Collector current (Pulse)	I _{CM}	150	А	$C_M = 400 \ \mu F$
				(see performance curve)
Junction temperature	Tj	- 40 to +150	°C	
Storage temperature	Tstg	- 40 to +150	°C	

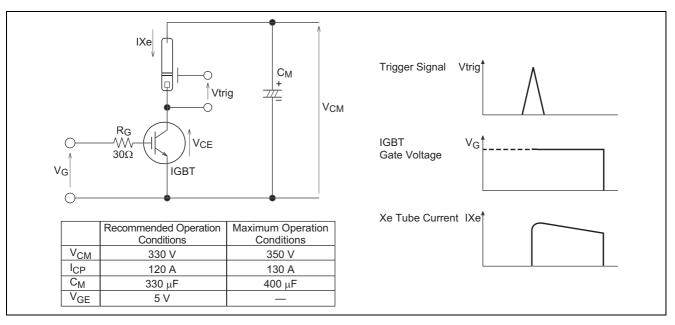
Electrical Characteristics

						$(Tch = 25^{\circ}C)$
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions
Collector-emitter breakdown voltage	V _{(BR)CES}	450	—	—	V	$I_C = 1 \text{ mA}, V_{GE} = 0 \text{ V}$
Gate-emitter breakdown voltage	$V_{(BR)GES}$	±8	—	—	V	$I_G=\pm 100~\mu\text{A},~V_{CE}=0~\text{V}$
Collector-emitter leakage current	ICES	—	—	10	μA	$V_{CE} = 400 \text{ V}, V_{GE} = 0 \text{ V}$
Gate-emitter leakage current	I _{GES}	—	—	±10	μA	$V_{GE} = \pm 6 \text{ V}, V_{CE} = 0 \text{ V}$
Gate-emitter threshold voltage	$V_{\text{GE(th)}}$	_	_	1.5	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$

Performance Curves



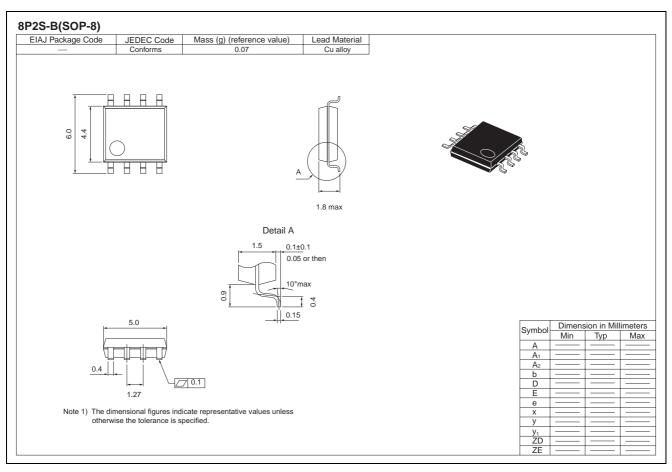
Application Example



Precautions on Usage

- 1. IGBT has MOS structure and its gate is insulated by thin silicon oxide. So please handle carefully to protect the device from electrostatic charge.
- 2. Gate drive voltage during on-period must be applied to satisfy the rating of maximum pulse collector current. And peak reverse gate current during turn-off must become less than 0.1A. (In general, when $R_{G (off)} = 30 \Omega$, it is satisfied.)
- 3. The operation life should be endured 5,000 shots under the charge current ($I_{Xe} \le 150 \text{ A}$: full luminescence condition) of main capacitor ($C_M = 400 \ \mu\text{F}$) which can endure repeated discharge of 5,000 times. Repetition period under full luminescence condition is over 3 seconds.
- 4. Total operation hours applied to the gate-emitter voltage must be within 5,000 hours.

Package Dimensions



Order Code

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Surface-mounted type	Taping	3000	Type name – T +Direction (1 or 2)+3	CY25AAJ-8F-T13
Surface-mounted type Plastic Magazine (Tube)		100	Type name	CY25AAJ-8F

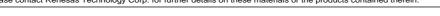
Note : Please confirm the specification about the shipping in detail.

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